Product data sheet

1. General description

N-channel enhancement mode Field-Effect Transistor (FET) in a leadless ultra small DSN1006-3 (SOT8026) Surface-Mounted Device (SMD) package using Trench MOSFET technology.

2. Features and benefits

- Low threshold voltage
- Very fast switching
- Ultra small package: 1 × 0.6 × 0.2 mm
- Trench MOSFET technology

3. Applications

- · Battery switch
- · High-speed line driver
- Low-side load switch
- · Switching circuits

4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions		Min	Тур	Max	Unit	
V _{DS}	drain-source voltage	T _j = 25 °C		-	-	30	V	
V_{GS}	gate-source voltage			-12	-	12	V	
I _D	drain current	V _{GS} = 4.5 V; T _{amb} = 25 °C; t ≤ 5 s	[1]	-	-	4.8	Α	
Static characte	Static characteristics							
R _{DSon}	drain-source on-state resistance	$V_{GS} = 4.5 \text{ V}; I_D = 4 \text{ A}; T_j = 25 ^{\circ}\text{C}$		-	40	50	mΩ	

^[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and mounting pad for drain 6 cm².



30 V, N-channel Trench MOSFET

5. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	G	gate		
2	S	source	2 1 1	
3	D	drain		
			Transparent top view DSN1006 (SOT8026)	G D D D D D D D D D D D D D D D D D D D

6. Ordering information

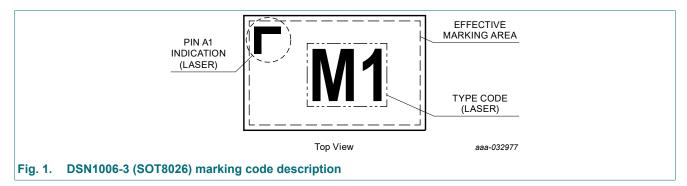
Table 3. Ordering information

Type number	Package						
	Name	Description	Version				
PMCB60XN	DSN1006	chip-scale package; 3 terminals; body 1.0 x 0.6 x 0.2 mm	SOT8026				

7. Marking

Table 4. Marking codes

Type number	Marking code
PMCB60XN	M1



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8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
V _{DS}	drain-source voltage	T _j = 25 °C		-	30	V
V _{GS}	gate-source voltage			-12	12	V
I _D	drain current	V _{GS} = 4.5 V; T _{amb} = 25 °C; t ≤ 5 s	[1]	-	4.8	Α
		V _{GS} = 4.5 V; T _{amb} = 25 °C	[1]	-	4	Α
		V _{GS} = 4.5 V; T _{amb} = 100 °C	[1]	-	2.5	Α
I _{DM}	peak drain current	T_{amb} = 25 °C; single pulse; $t_p \le 10 \mu s$		-	16	Α
P _{tot}	total power dissipation	T _{amb} = 25 °C	[2]	-	480	mW
			[1]	-	1	W
		T _{sp} = 25 °C		-	7	W
T _j	junction temperature			-55	150	°C
T _{amb}	ambient temperature			-55	150	°C
T _{stg}	storage temperature			-65	150	°C
Source-drai	n diode			'		•
I _S	source current	T _{amb} = 25 °C	[1]	-	1.2	Α

- [1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and mounting pad for drain 2 .
- [2] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.

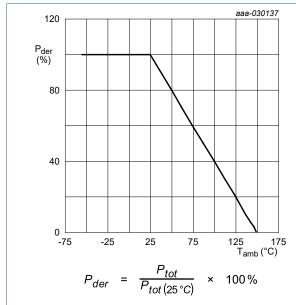


Fig. 2. Normalized total power dissipation as a function of ambient temperature

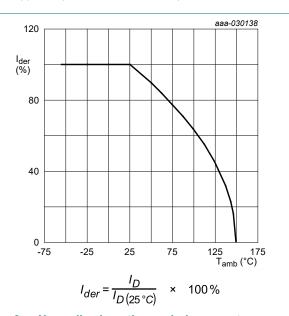


Fig. 3. Normalized continous drain current as a function of ambient temperature

30 V, N-channel Trench MOSFET

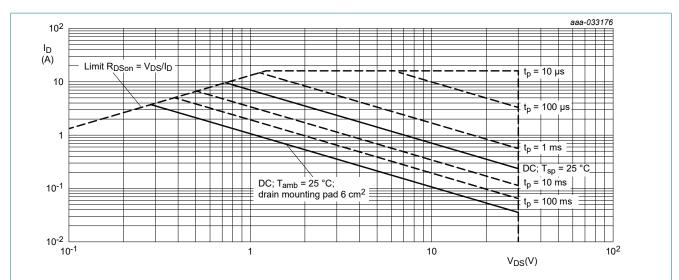


Fig. 4. Safe operating area; junction to ambient; continuous and peak drain currents as a function of drain-source voltage

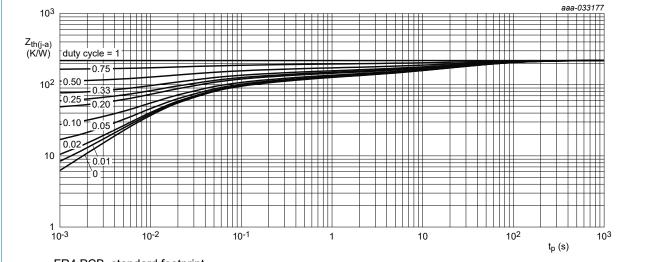
30 V, N-channel Trench MOSFET

9. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
uiy-a)	thermal resistance from	in free air	[1]	-	220	258	K/W
	junction to ambient		[2]	-	102	120	K/W
		in free air; t ≤ 5 s	[2]	-	60	70	K/W
R _{th(j-sp)}	thermal resistance from junction to solder point			-	13	18	K/W

- [1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.
- Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and mounting pad for drain 6 cm².



FR4 PCB, standard footprint

Fig. 5. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values

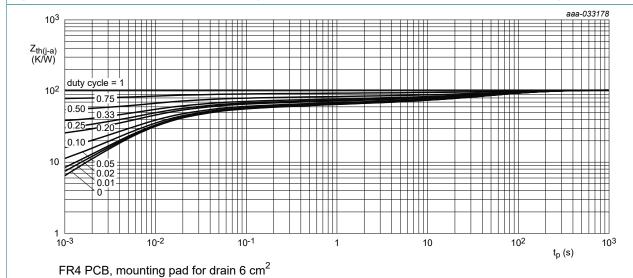


Fig. 6. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values

30 V, N-channel Trench MOSFET

10. Characteristics

Table 7. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static chara	cteristics					
V _{(BR)DSS}	drain-source breakdown voltage	$I_D = 250 \mu A; V_{GS} = 0 V; T_j = 25 °C$	30	-	-	V
V_{GSth}	gate-source threshold voltage	$I_D = 250 \mu A; V_{DS} = V_{GS}; T_j = 25 \text{ °C}$	0.6	0.8	1.1	V
I _{DSS}	drain leakage current	$V_{DS} = 30 \text{ V}; V_{GS} = 0 \text{ V}; T_j = 25 ^{\circ}\text{C}$	-	-	1	μΑ
I _{GSS} gate leakage current	V _{GS} = 12 V; V _{DS} = 0 V; T _j = 25 °C	-	-	100	nA	
		V _{GS} = -12 V; V _{DS} = 0 V; T _j = 25 °C	-	-	-100	nA
R _{DSon}	drain-source on-state	$V_{GS} = 4.5 \text{ V}; I_D = 4 \text{ A}; T_j = 25 ^{\circ}\text{C}$	-	40	50	mΩ
	resistance	V _{GS} = 4.5 V; I _D = 4 A; T _j = 150 °C	-	61	76	mΩ
		V _{GS} = 2.5 V; I _D = 2 A; T _j = 25 °C	-	48	65	mΩ
	V _{GS} = 1.8 V; I _D = 0.5 A; T _j = 25 °C	-	65	120	mΩ	
9 _{fs}	forward transconductance	$V_{DS} = 10 \text{ V}; I_D = 4.8 \text{ A}; T_j = 25 \text{ °C}$	-	8	-	S
R _G	gate resistance	f = 1 MHz	-	1.6	-	Ω
Dynamic ch	aracteristics				·	
Q _{G(tot)}	total gate charge	V _{DS} = 15 V; I _D = 4.8 A; V _{GS} = 4.5 V;	-	2	2.7	nC
Q _{GS}	gate-source charge	T _j = 25 °C	-	0.4	-	nC
Q_GD	gate-drain charge		-	0.5	-	nC
C _{iss}	input capacitance	$V_{DS} = 15 \text{ V; } f = 1 \text{ MHz; } V_{GS} = 0 \text{ V;}$	-	241	-	pF
C _{oss}	output capacitance	T _j = 25 °C	-	117	-	pF
C _{rss}	reverse transfer capacitance		-	15	-	pF
t _{d(on)}	turn-on delay time	V_{DS} = 15 V; I_D = 4.8 A; V_{GS} = 4.5 V;	-	2	-	ns
t _r	rise time	$R_{G(ext)} = 6 \Omega; T_j = 25 ^{\circ}C$	-	4	-	ns
t _{d(off)}	turn-off delay time	1	-	5	-	ns
t _f	fall time	1	-	2	-	ns
Source-drai	n diode		'			'
V_{SD}	source-drain voltage	I _S = 1.2 A; V _{GS} = 0 V; T _i = 25 °C	-	0.7	1.2	V

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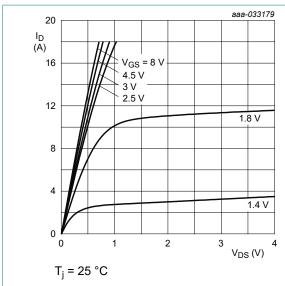


Fig. 7. Output characteristics: drain current as a function of drain-source voltage; typical values

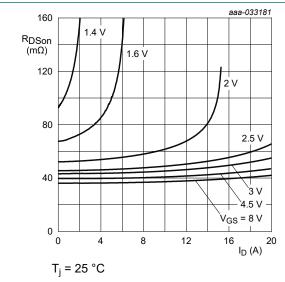


Fig. 9. Drain-source on-state resistance as a function of drain current; typical values

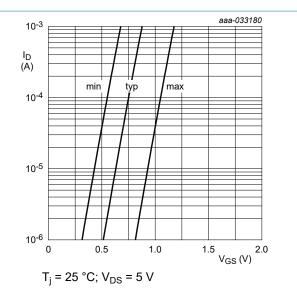


Fig. 8. Subthreshold drain current as a function of gate-source voltage

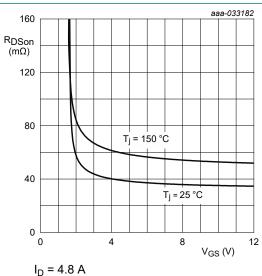


Fig. 10. Drain-source on-state resistance as a function of gate-source voltage; typical values

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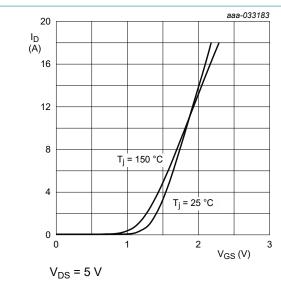


Fig. 11. Transfer characteristics: drain current as a function of gate-source voltage; typical values

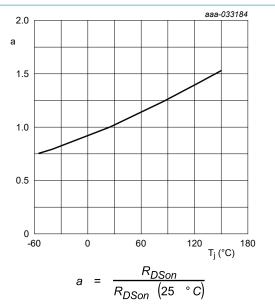


Fig. 12. Normalized drain-source on-state resistance as a function of junction temperature; typical values

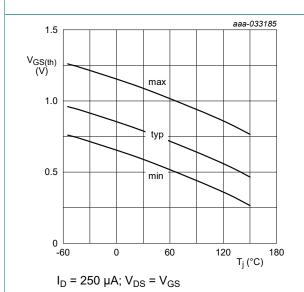
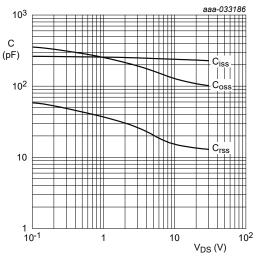


Fig. 13. Gate-source threshold voltage as a function of junction temperature



 $f = 1 MHz; V_{GS} = 0 V$

Fig. 14. Input, output and reverse transfer capacitances as a function of drain-source voltage; typical values

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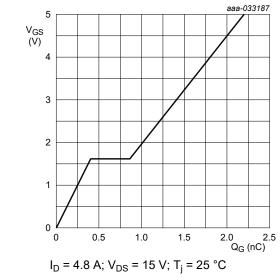


Fig. 15. Gate-source voltage as a function of gate charge; typical values

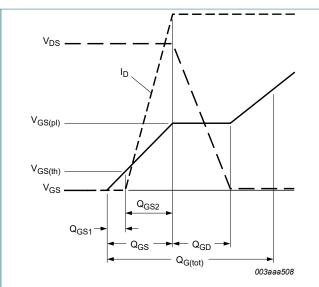


Fig. 16. Gate charge waveform definitions

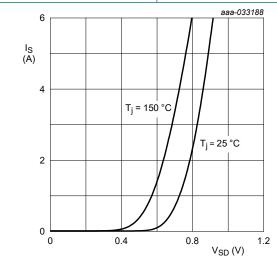
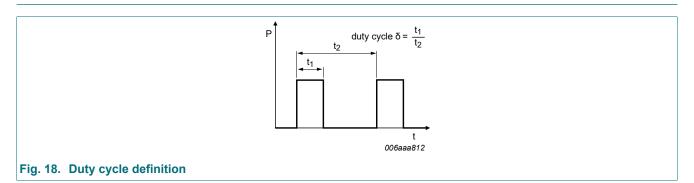


Fig. 17. Source current as a function of source-drain voltage; typical values

11. Test information

 $V_{GS} = 0 V$



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12. Package outline

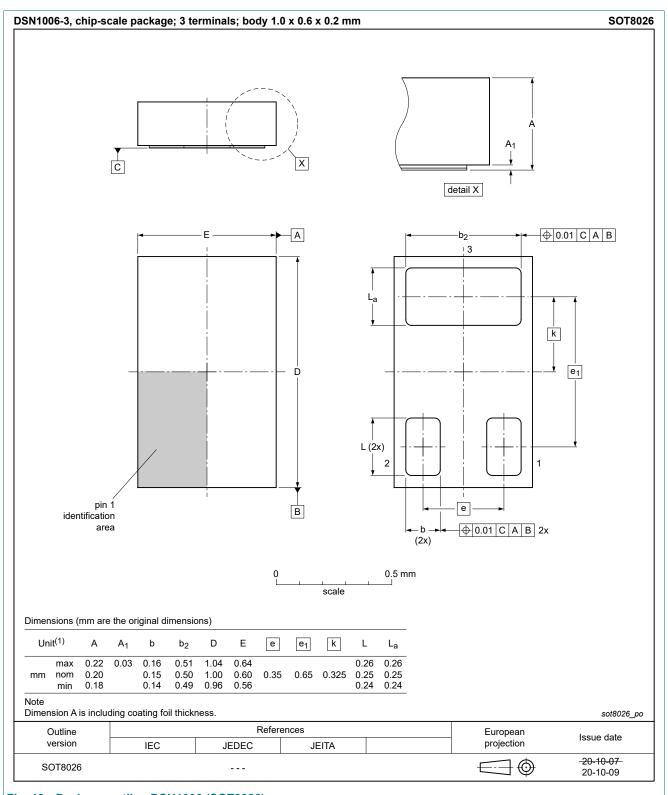
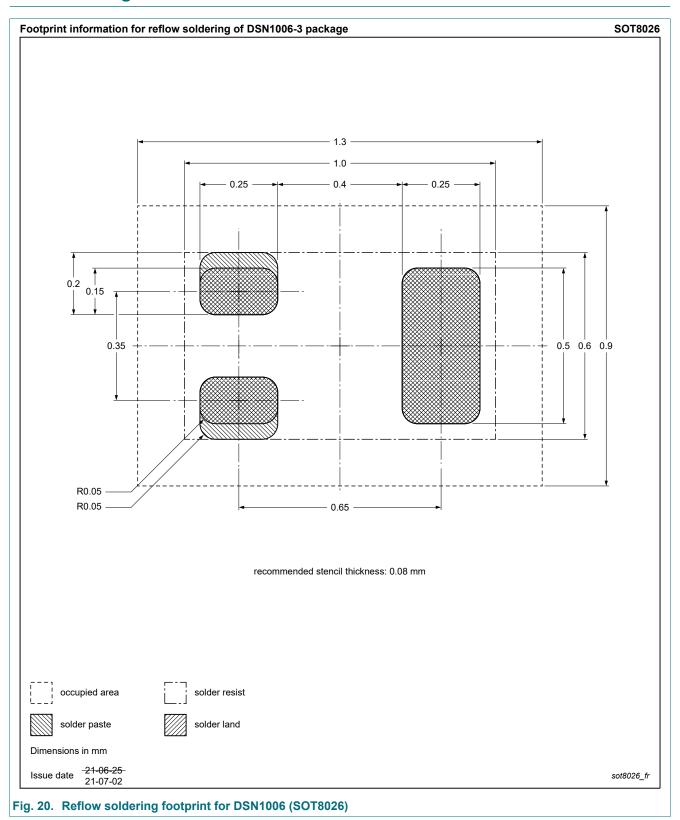


Fig. 19. Package outline DSN1006 (SOT8026)

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13. Soldering



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14. Revision history

Table 8. Revision history

Data sheet ID	Release date	Data sheet status	Change notice	Supersedes
PMCB60XN v.1	20210720	Product data sheet	-	-

30 V, N-channel Trench MOSFET

15. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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- [2] The term 'short data sheet' is explained in section "Definitions".
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